

**isc N-Channel MOSFET Transistor**
**FDP15N65**
**FEATURES**

- Drain Current :  $I_D = 15A @ T_C = 25^\circ C$
- Drain Source Voltage :  $V_{DSS} = 650V(\text{Min})$
- Static Drain-Source On-Resistance :  $R_{DS(on)} = 0.44 \Omega (\text{Max}) @ V_{GS} = 10V$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**DESCRIPTION**

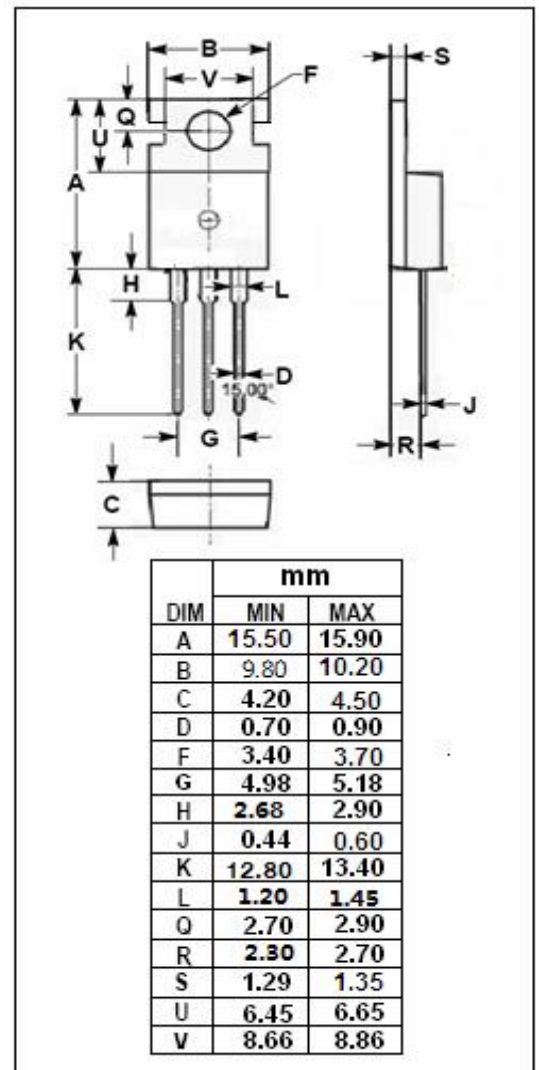
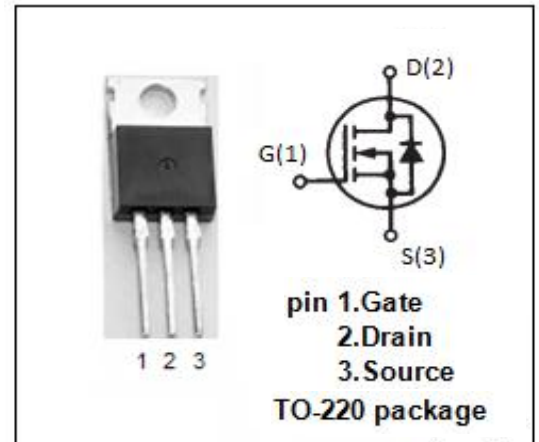
- motor drive, DC-DC converter, power switch and solenoid drive.

**ABSOLUTE MAXIMUM RATINGS( $T_a = 25^\circ C$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	650	V
$V_{GS}$	Gate-Source Voltage-Continuous	$\pm 30$	V
$I_D$	Drain Current-Continuous	15	A
$I_{DM}$	Drain Current-Single Pluse	60	A
$P_D$	Total Dissipation @ $T_C = 25^\circ C$	38.5	W
$T_J$	Max. Operating Junction Temperature	-55~150	$^\circ C$
$T_{stg}$	Storage Temperature	-55~150	$^\circ C$

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(j-c)}$	Thermal Resistance, Junction to Case	3.3	$^\circ C/W$



## isc N-Channel MOSFET Transistor

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## ELECTRICAL CHARACTERISTICS

T<sub>C</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	650	-	V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> = 0.25mA	3.0	5.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =7.5A	-	0.44	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V; V <sub>DS</sub> = 0	-	±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =650V; V <sub>GS</sub> = 0	-	1	uA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> =15A; V <sub>GS</sub> = 0	-	1.4	V

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